Transition from Dirac Points to Exceptional Points in Anisotropic Waveguides

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We uncover the existence of Dirac and exceptional points in waveguides made of anisotropic materials, and study the transition between them. Dirac points in the dispersion diagram appear at propagation directions where the matrix describing the eigenvalue problem for bound states splits into two blocks, sorting the eigenmodes either by polarization or by inner mode symmetry. Introducing a non-Hermitian channel via a suitable leakage mechanism causes the Dirac points to transform into exceptional points connected by a Fermi arc. The exceptional points arise as improper hybrid leaky states and, importantly, are found to occur always out of the anisotropy symmetry planes.

Many physical phenomena that initially arose in quantum and solid-state physics and where rare bound states and special dispersion properties play a central role have found important and fertile implementations in optical systems. Chiral edge states [1, 2], Weyl points [3], topological insulators [4–9], or bound states in the continuum [10–12], to cite only a few, are examples of effects that have opened rich lines of research that are of continuously growing interest for both, the fundamental understanding of wave phenomena and its application to photonic devices. Occurrence of Dirac points (DPs) and exceptional points (EPs) are another salient example.

By and large, Dirac points are singularities in the band diagrams of Hermitian systems that are at the core of the unique properties of the corresponding structures and materials, as for example in the electronic properties of graphene [13]. A DP occurs when two bands cross each other locally and exhibit a linear dispersion in any direction in the momentum space [1]. As the eigenvalues of Hermitian systems are real, two orthogonal eigenstates coexist at the DP with the same eigenvalue. The counterpart in non-Hermitian systems are exceptional points [14], where the complex eigenvalues of two different bands are identical, with equal real and imaginary parts. In EPs, the eigenvectors and therefore the bands are also degenerate. Thus, at an EP the matrix describing the system in standard formalism as an eigenvalue problem cannot be diagonalized. Such properties result in unique dynamics near EPs [15], which result in, e.g., asymmetric mode switching [16, 17], appearance of polarization topological half-charges [18], chiral modes and directional lasing [19], or ultrasensitive measurements [20, 21].

Adding a non-Hermitian physical effect transforms DPs into EPs [22]. Studying the transition between them requires a system where DPs exist and EPs can be generated by opening a non-conservative channel. In this Letter we address the existence conditions of DPs in waveguiding structures containing uniaxial anisotropic materials and study their transformation into EPs when a tunable leakage mechanism opens a radiation channel. Encircling the EPs can be conceptually done by varying the optical axis orientation relative to the propagation direction of the material forming the waveguide core.

The existence of DPs in waveguiding structures can be elucidated by analysing the matrix describing the eigenvalue problem for bound states. Waveguides with isotropic materials are described by two independent matrices for Transverse Electric (TE) and Magnetic (TM) eigenmodes. This results in lines in the dispersion diagram that do not cross each other, therefore DPs do not exist. In contrast, general structures made of anisotropic materials are described by a matrix that cannot be separated in smaller parts, resulting in the intrinsic hybrid polarization of the eigenmodes. Solving the eigenvalue problem as a function of the propagation direction results into eigenmodes that exist in surfaces (bands) in the three dimensional dispersion diagram [Fig.2(a)]. However, under suitable material or geometrical symmetric...
Mode crossings in waveguides made of anisotropic media are known to exist, see e.g., [25–28]. However, it must be properly appreciated that to date none of such crossings have been identified as a DP and, more importantly, most crossings are not DPs, actually. For example, the matrix describing the waveguide studied in Fig. 2 splits into two blocks for two other configurations: when the optical axis is oriented orthogonal (θ = 0°) and parallel (θ = 90°) to the structure interface, resulting into pure TE/TM and even/odd eigenmodes, respectively [29]. However, none of such cases correspond to a DP, because the splitting of the matrix, and therefore the surface crossing, appear for any propagation direction within the waveguide plane, and not at specific directions, thus failing to show the linear dispersion dependence required for a DP.

Dirac points transform into EPs by introducing gain or losses in the system [18, 22, 23]. Thus, we open a non-conservative channel by placing a region with a high refractive index close to the film, which causes energy to leak away. The high refractive index may be provided by a suitable bulk material or may be induced externally, e.g., by a thermooptic effect. The loss strength is dictated by the penetration of the evanescent tails into the high-index material and, importantly, also by the optical axis orientation, which affects the hybrid composition of the eigenmodes in terms of ordinary and extraordinary waves and thus the fraction of total energy carried by the component that becomes leaky. In the analysis, we set the refractive indices, the wavelength and the thickness of the waveguide, and vary the optical axis orientation.

Figure 3(a) shows the two bands existing above cutoff in the structure corresponding to Fig. 2 for d/λ = 0.5.
FIG. 3. (a) Dispersion for the waveguide in Fig. 2 as a function of $\theta$ and $\phi$ with $d/\lambda = 0.5$. (b) Same as in (a) but now for a structure with $n_b = 1.8$ located at a distance from the film $d_b/\lambda = 0.5$. The colour scale in (b) is proportional to the normalized decay length.

FIG. 4. (a), (b) Angular loci of the DPs (red) and EPs (blue) as a function of $n_b$ for $d_b/\lambda = 0.5$. The insets expand the transition regions; the apparent gap in the inset of (a) is due to the finite resolution of the calculations. Red and blue dots correspond to Fig.3(a) and 3(b), respectively. Eigenmode of the (c) TE and (d) TM bound states at the DP. (e) Field components of the hybrid leaky mode near the EP.

The bands touch each other in a DP located at the optical axis orientation ($\theta = 75.6^\circ, \phi = 0^\circ$), where the eigenmodes are separable by polarization. Rising the refractive index from $n_b = n_s = 1.4$ to $n_b < N$ only changes the optical axis polar orientation $\theta$ at which the DP exists [Fig. 4(a)]. Yet, the system remains Hermitian, the DP is found at the symmetry plane $\phi = 0^\circ$, and the polarization remains either TE [Fig. 4(c)] or TM [Fig. 4(d)]. In contrast, when $n_b > N$ a radiation channel is opened and the system becomes non-Hermitian. Then, the eigenmodes become improper hybrid leaky modes with complex $N$, and the DP transforms into a pair of EPs that, therefore, occur out of the anisotropy symmetry planes.

For slightly larger values of $n_b$, the two EPs occur closer to each other (see the inset) and, as $n_b$ keeps increasing, the loci at which the EPs are located depart further from the symmetry plane $\phi \neq 0^\circ$ [Fig. 4(b)]. A representative shape of the dispersion diagram of the leaky modes for $n_b = 1.8$, featuring two EPs located at $\theta = 77.78^\circ$, $\phi = \pm 2.49^\circ$, is shown in Fig. 3(b). At the EPs the bands coalesce, with $N$ having identical real and imaginary parts. The real part of the effective index of the leaky modes is identical at both bands in the line connecting the two EPs, a property that is equivalent to a Fermi arc in the energy-momentum dispersion diagram. The imaginary part of $N$ differs along the Fermi arc for the two bands, except at the EP where the modes are completely degenerate. These EPs are hybrid states [Fig. 4(e)] and are located at directions where the optical axis is oriented out of any anisotropy symmetry plane of the structure. We found that the TE/TM projections of the hybrid modes around the EPs remains almost constant, with the TM fraction being larger (almost twice in the particular case shown) than the TE polarization.

The mechanism that splits the matrix that describes the system impacts the robustness of the DPs against perturbations. DPs arising between bands with different polarization are robust even against asymmetric perturbations, as the system matrix can be split in any case. This yields the dispersion diagram shown in Fig. 5(a), which corresponds to a waveguide that is asymmetric in terms of the refractive index. However, DPs arising between bands with different parity cease to exist in the presence of asymmetric perturbations, as in such a case.
the system matrix can only be divided into blocks when the waveguide is symmetric, as elaborated in the Appendix. As a consequence, a gap opens in the dispersion band diagram of asymmetric structures [Fig. 5(b)]. In contrast, EPs are robust against perturbations and do appear in asymmetric non-Hermitian structures. Fig. 5(c) shows the two EPs related to the DP arising between bands with different polarization when the structure in 5(a) is coupled to an isotropic background. In contrast to simple expectations, Fig. 5(d) also shows two EPs, even when a gap was present between the two bands with different parity in Fig. 5(b). In this case the origin of EPs must be seek in the DPs arising in symmetric structure rather than in the asymmetric one.

Note that robustness of EPs has been related to the topological properties exhibited by the corresponding radiated fields [18]. Fig. 6 shows the polarization of the radiated field for the structure analyzed in Fig. 5(c), for different isofrequency cuts in the dispersion diagram. The isofrequency surface that encircles the EPs (the panel with green frame in Fig. 6(b)) shows the half-charge polarization winding near the EP described in [18]. A half topological charge is apparent starting from the vertical red polarization, traversing the full contour in the clockwise direction and returning to the same point. Then the polarization flips direction by rotating 180° in the clockwise direction.

The transition from a Hermitian to a non-Hermitian behavior allows comparing the dynamical evolution in the proximity of DPs and EPs. In the anisotropic waveguides, this can be done by varying the optical axis orientation in the film along the propagation direction [Fig. 7(a)]. We performed Finite-Difference-Time-Domain (FDTD) calculations [34] along a closed circuit in the \( \theta - \phi \) parameter space in a clock- and anti-clockwise direction, which is equivalent to excite the structure from the right or left sides, and study reversal (direction-independent) versus chiral (direction-dependent) mode conversion [16, 30–32]. In the Hermitian structure, the linear dispersion at the DP allows exchanging the band while maintaining the polarization, and the anti-crossing existing in their proximity (Fig. 2(b,c)) results in polarization conversion [33]. We therefore chose an arbitrary (i.e., by no means optimized) closed circuit that crosses trough the DP and returns through an anti-crossing. A direct consequence of the election of a circuit that crosses a DP is conversion from a TE (TM) input to a TM (TE) output after returning at the initial point [Fig. 7(b)]. The conversion is total and independent of the direction of excitation when the change in optical axis orientation is adiabatic, which in the case of the figure occurs for propagation lengths larger that 100\( \lambda \). In the case of a circuit containing a DP between bands with different parity [Fig. 2(c)], the conversion refers to the parity state.

When \( n_b \) increases, the circuit encircles the EP in a non-Hermitian way. The change of polarization still occurs, as the branches are exchanged through the Fermi arc. However, the conversion now is chiral and depends on the propagation direction. The phenomenon occurs also with low losses, when the leakage mechanism is introduced only in one section of the circuit [the red square in Fig. 7(c)]. Chiral conversion is illustrated in Fig. 7(d), where the conversion from TE (TM) input to TM (TE) output yields a different value when the waveguide is excited from the right or from the left side. In this particular case the non-Hermitian section is short and it is located at the center of the waveguide, which is enough to expose the occurrence of the chiral behavior. However, its absolute strength may be enhanced by optimizing the location and length of the section containing the radiative channel.

To summarize, we stress that the new feature introduced in this Letter is the existence of DPs and EPs in waveguiding structures made of anisotropic materials. The anisotropy introduces intrinsic angular-dependent propagation properties, which allows the existence of EPs out of symmetry planes, and affords the possibility to follow the transition between DPs and EPs by opening and closing a suitable non-conservative channel. The transition from the Hermitian to a non-Hermitian behavior occurs via a radiation channel that generates leaky modes that are hybrid (with the full field components) and improper (they are modes of infinite energy that capture the physics of a infinite band of proper modes belonging to the continuum spectrum), which break the Hermitian behavior through radiation rather than via material losses. Such a physical mechanism is general and
FIG. 7. Hermitian vs non-Hermitian dynamical evolution modelled with FDTD. (a) Variation of the film optical axis orientation along the \( y \) axis used in all the calculations: The optical axis follows a closed circuit in the \( \theta - \phi \) parameter space. The calculations were performed for the waveguide characteristics as in Fig. 3. (b) Mode conversion for the Hermitian structure as a function of the device length when a TM (left panel) and TE (right panel) mode is injected from the left (circles) and the right (asterisk) side of the structure. (c) Example of FDTD propagation combining Hermitian and non-Hermitian (red square) sections in the same structure. (d) Same as in (b) but when the central part of the structure is non-Hermitian.

should be applicable to other types of photonic structures showing similar phenomena, as is the case of photonic crystals with a graphene-like lattice [35–38]. We studied a simple structure made of film birefringent materials, but the concept holds for more complex structures, including waveguides made of biaxial materials, of multiple anisotropic layers that allow a higher control of radiation, and of general anisotropic metamaterials.

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APPENDIX: SPLITTING OF THE SYSTEM MATRIX

The dielectric tensor of a uniaxial material for an arbitrary orientation of the optical axis given by the angles \( \theta \) and \( \phi \) as defined in Fig. 2(a) of the main text reads as

\[
\epsilon = \begin{bmatrix}
\epsilon_{xx} & \epsilon_{xy} & \epsilon_{xz} \\
\epsilon_{xy} & \epsilon_{yy} & \epsilon_{yz} \\
\epsilon_{xz} & \epsilon_{yz} & \epsilon_{zz}
\end{bmatrix} = \begin{bmatrix}
\epsilon_e \cos^2 (\theta) + \epsilon_o \sin^2 (\theta) & \Delta \sin (\theta) \cos (\phi) \cos (\theta) & \Delta \sin (\phi) \sin (\theta) \cos (\theta) \\
\Delta \sin (\theta) \cos (\phi) \cos (\theta) & \Delta \sin^2 (\theta) \cos^2 (\phi) + \epsilon_o & \Delta \sin (\phi) \sin^2 (\theta) \cos (\phi) \\
\Delta \sin (\phi) \sin (\theta) \cos (\theta) & \Delta \sin (\phi) \sin^2 (\theta) \cos (\phi) & \Delta \sin^2 (\phi) \sin^2 (\theta) + \epsilon_o
\end{bmatrix},
\]

(1)

where \( \epsilon_o = n_o^2 \) and \( \epsilon_e = n_e^2 \) are the ordinary and the extraordinary dielectric constants, respectively, and \( \Delta = \epsilon_e - \epsilon_o \). Following Berreman’s approach [39, 40], Maxwell equations are solved using the electric and magnetic field components parallel to the interfaces. For propagation along \( y \), monochromatic waves take the form

\[
\vec{E}(x, y, t) = \vec{E} \cdot e^{i(k_0(\kappa_xx + N_y) - \omega t)} \\
\vec{H}(x, y, t) = \vec{H} \cdot e^{i(k_0(\kappa_xx + N_y) - \omega t)},
\]

(2)

with \( k_0 \) being the vacuum wavenumber. In an isotropic material with dielectric constant \( \epsilon \), the solutions reduce to TE and TM sets, with eigenvalues \( \kappa_x = \kappa = \pm \sqrt{\epsilon - k^2_y} \), for forward (+ sign) and backward (- sign) propagation. Then the field amplitudes in (2) can be described using a column vector \( \vec{F} \) as

\[
\vec{F} = \begin{bmatrix}
E_y \\
H_x \\
E_z \\
H_y
\end{bmatrix}, \quad \vec{F}_{TE} = \begin{bmatrix}
1 \\
\frac{\epsilon}{\kappa} \\
0 \\
0
\end{bmatrix}, \quad \vec{F}_{TM} = \begin{bmatrix}
0 \\
0 \\
1 \\
-\kappa
\end{bmatrix}.
\]

(3)
In anisotropic uniaxial materials the solutions are ordinary and extraordinary waves. Here we use the corresponding analytic expression derived in [24] with ordinary \( \kappa_o \) and extraordinary \( \kappa_e \) eigenvalues

\[
\kappa_o = \pm \sqrt{\epsilon - k_0^2},
\]

(4)

\[
\kappa_e = -\frac{1}{\epsilon_{xx}} \left( \epsilon_{xy} k_y + \sqrt{\epsilon_o (\epsilon_{xx} + k_o^2 (\epsilon_e - \epsilon_o))} \right),
\]

(5)

with

\[
\vec{F}_o = \begin{bmatrix}
\kappa_o \sin(\phi) \sin(\theta) \\
\epsilon_o \sin(\phi) \sin(\theta) \\
k_y \cos(\theta) - \kappa_o \cos(\theta) \cos(\phi) \\
-\kappa_o (k_y \cos(\theta) - \kappa_o \sin(\theta) \cos(\phi))
\end{bmatrix},
\]

\[
\vec{F}_e = \begin{bmatrix}
-\kappa_e \kappa_o \cos(\phi) + \kappa_o^2 \sin(\phi) \cos(\phi) \\
\epsilon_o (\kappa_e \cos(\phi) + \kappa_o \sin(\phi) \cos(\phi)) \\
\epsilon_o (\kappa_e \cos(\phi) + \kappa_o \sin(\phi) \cos(\phi)) \\
-\epsilon_o \kappa_e \sin(\phi) \sin(\theta)
\end{bmatrix}.
\]

(6)

Following Berreman’s approach, a layer of material is accounted for by its field 4x4 matrix \( \vec{F} \), composed by the four field vectors \( \vec{F} \) representing the forward (+ superindex) and backward (- superindex) waves

\[
\vec{F}_{iso} = [\vec{F}_{TE}^+, \vec{F}_{TE}^-, \vec{F}_{TM}^+, \vec{F}_{TM}^-],
\]

\[
\vec{F}_{ux} = [\vec{F}_e^+, \vec{F}_e^-, \vec{F}_o^+, \vec{F}_o^-].
\]

(7)

The optical response of a multilayer system is described by the characteristic matrix \( \hat{A} \) calculated as

\[
\hat{A} = \check{F}_e^{-1} \hat{M} \check{F}_s,
\]

(8)

where \( \check{F}_e \) and \( \check{F}_s \) are the cladding and substrate field matrices respectively, and \( \hat{M} \) is defined for a stack of \( N \) layers as

\[
\hat{M} = \check{F}_1 \hat{A}_1 \check{F}^{-1}_1 \check{F}_2 \hat{A}_2 \check{F}^{-1}_2 ... \check{F}_N \hat{A}_N \check{F}^{-1}_N 1^{-1}.
\]

(9)

The diagonal matrix \( \hat{A}_i \) is the phase matrix of layer \( i \), which in an isotropic layer writes

\[
\hat{A}_i = \begin{bmatrix}
e^{id_i k_o k} & 0 & 0 & 0 \\
0 & e^{-id_i k_o k} & 0 & 0 \\
0 & 0 & e^{id_i k_o k} & 0 \\
0 & 0 & 0 & e^{-id_i k_o k}
\end{bmatrix},
\]

(10)

and in an uniaxial layer it writes

\[
\hat{A}_i = \begin{bmatrix}e^{id_i k_o k} & 0 & 0 & 0 \\
0 & e^{id_i k_o k} & 0 & 0 \\
0 & 0 & e^{id_i k_o k} & 0 \\
0 & 0 & 0 & e^{-id_i k_o k}
\end{bmatrix},
\]

(11)

with \( d_i \) being the thickness of the \( i \)th layer.

For guided modes, the evanescent waves in the cladding are related to the evanescent waves of the substrate by the characteristic matrix as

\[
A_{TE,s}^+ \vec{F}_{TE}^s + A_{TM,s}^+ \vec{F}_{TM}^s = \hat{M} (A_{TE,c}^- \vec{F}_{TE}^- + A_{TM,c}^- \vec{F}_{TM}^-),
\]

(12)

where \( A_{TE,s}^+ \) and \( A_{TM,s}^+ \) are the amplitudes of the forward TE and TM waves in the substrate and \( A_{TE,c}^- \) and \( A_{TM,c}^- \) the amplitudes of the backward propagating TE and TM waves in the cladding. This results in a system of equations describing the eigenvalue problem, characterized by the system matrix.

The calculation of \( \hat{M} \) can be readily done numerically. However, it is instructive to derive the modal equation from the boundary conditions for a layer system comprising a uniaxial film and isotropic cladding and substrate, and write it in the form of a 8x8 matrix. At the interface between the substrate and the film, the boundary conditions write

\[
A_{TE,s}^+ \vec{F}_{TE}^s + A_{TM,s}^+ \vec{F}_{TM}^s = A_{TE,c}^- \vec{F}_{TE}^- e^{id x k_{0} k} + A_{TM,c}^- \vec{F}_{TM}^- e^{id y k_{0} k} + \vec{A}_e^+ + \vec{A}_o^+ e^{id x k_{0} k} + \vec{A}_e^- + \vec{A}_o^- e^{id y k_{0} k},
\]

(13)

and at the interface between cladding and film they write

\[
A_{TE,c}^- \vec{F}_{TE}^- + A_{TM,c}^- \vec{F}_{TM}^- = A_{TE,c}^+ \vec{F}_{TE}^+ e^{-id x k_{0} k} + A_{TM,c}^+ \vec{F}_{TM}^+ e^{-id y k_{0} k} + \vec{A}_e^- + \vec{A}_o^- e^{-id x k_{0} k} + \vec{A}_e^+ + \vec{A}_o^+ e^{-id y k_{0} k},
\]

(14)

where \( \vec{A}_e^\pm \), \( \vec{A}_o^\pm \), \( \vec{A}_e^- \) and \( \vec{A}_o^- \) are the amplitudes of the four waves in the film.

Equations (13) and (14) can be written as a 8x8 matrix, the determinant of which yields the eigenvalue equation. In general, modes need all 8 amplitudes, and the whole matrix cannot be separated into smaller blocks. Thus, anisotropy couples the eight waves. However, under special conditions the matrix can be written as 4x4 blocks. Then the system matrix takes the form

\[
\begin{bmatrix}
\vec{B}_1 & \vec{O}_1 \\
\vec{O}_2 & \vec{B}_2
\end{bmatrix} \vec{A}_m = \vec{0}.
\]

(15)

Specifically, for \( \phi = 0^\circ \) (\( x - y \) plane), the 8x8 matrix splits by polarization, corresponding to the case shown in Fig. 3(a). Under such conditions, all components in \( \vec{O}_1 \) and \( \vec{O}_2 \) vanish, even for asymmetric structures (Fig. 5(a)). Then, DPs exist in both situation as the matrix can be split in two blocks. For the TE polarization one gets
Then, the diagonal blocks $\hat{B}_1$ and $\hat{B}_2$ in (15) write

$$\begin{bmatrix}
\hat{B}_1 & A_{TE, c}^+ & \hat{B}_2 & A_{TM, c}^+
\end{bmatrix} = \begin{bmatrix}
1 & (k_y + k_s \cos (\theta) + k_s \sin (\theta)) e^{i\frac{\kappa_s}{k_s} \kappa_s} & 0 & 0 \\
-k_s & -k_s & 0 & 0 \\
0 & -k_s & 0 & 0 \\
0 & -k_s & 0 & 0 \\
0 & -k_s & 0 & 0
\end{bmatrix} = \tilde{0}, \tag{16}
$$

and for $TM$ polarization one gets

$$\begin{bmatrix}
\hat{B}_1 & A_{TM, s} & \hat{B}_2 & A_{TM, c}
\end{bmatrix} = \begin{bmatrix}
1 & (k_y + k_s \cos (\theta) + k_s \sin (\theta)) e^{i\frac{\kappa_s}{k_s} \kappa_s} & 0 & 0 \\
-k_s & -k_s & 0 & 0 \\
0 & -k_s & 0 & 0 \\
0 & -k_s & 0 & 0 \\
0 & -k_s & 0 & 0
\end{bmatrix} = \tilde{0}. \tag{17}
$$

Another example of matrix splitting in blocks occurs at $\theta = 90^\circ \ (y - z \ planê)\), where eigenmodes can be described as odd and even modes. Algebraic combinations of the amplitudes $A_m$ lead to the new base

$$A_{TE, s}^{sum} = A_{TE, s}^+ + A_{TE, c}^-, \quad A_{TE, c}^{sub} = A_{TE, s}^+ - A_{TE, c}^-, \quad A_{TM, s}^{sum} = A_{TM, s}^+ + A_{TM, c}^-, \quad A_{TM, c}^{sub} = A_{TM, s}^+ - A_{TM, c}^-; \tag{18}
$$

Then, the diagonal blocks $\hat{B}_1$ and $\hat{B}_2$ in (15) write

$$\begin{bmatrix}
\hat{B}_1 & A_{TE, c}^+ & \hat{B}_2 & A_{TM, c}^+
\end{bmatrix} = \begin{bmatrix}
\frac{2}{\kappa_s} & 0 & -k_s & 0 \\
\frac{2}{\kappa_s} & 0 & -k_s & 0 \\
0 & 2 & \kappa_s & k_s \\
0 & 2 & \kappa_s & k_s
\end{bmatrix} = \tilde{0}. \tag{19}
$$

and

$$\begin{bmatrix}
\hat{B}_2 & A_{TM, s}^+ & \hat{B}_1 & A_{TM, c}^+
\end{bmatrix} = \begin{bmatrix}
\frac{2}{\kappa_s} & 0 & -k_s & 0 \\
\frac{2}{\kappa_s} & 0 & -k_s & 0 \\
0 & 2 & \kappa_s & k_s \\
0 & 2 & \kappa_s & k_s
\end{bmatrix} = \tilde{0}. \tag{20}
$$

In this case, blocks $\hat{O}_1$ and $\hat{O}_2$ in (15) are

$$\hat{O}_1 = \hat{O}_2 = \begin{bmatrix}
0 & 0 & 0 & 0 \\
0 & 0 & 0 & 0 \\
0 & 0 & 0 & 0 \\
0 & 0 & 0 & 0
\end{bmatrix}. \tag{21}
$$

These two blocks can vanish only when $\epsilon_s = \epsilon_c$ and $k_s = k_c$, i.e., when the substrate and cladding are identical and the amplitudes in (18) describe even and odd modes. If the waveguide is asymmetrical, the matrix (21) does not vanish and thus the system matrix (15) does not split in blocks and, therefore, DPs cannot exist. This is the case shown in Fig. 5(c), where instead of a DP, a gap is opened in the dispersion diagram.

Finally, another situation of interest occurs for $\phi = 90^\circ$. This corresponds to the DP shown in Figures 2(a) and 2(c) in the main text. Here one can use again the definitions in (18) to find the same blocks $\hat{O}_1$ and $\hat{O}_2$ as in (21), while the diagonal blocks $\hat{B}_1$ and $\hat{B}_2$ in (15) write

$$\begin{bmatrix}
\hat{B}_1 & A_{TE, c}^+ & \hat{B}_2 & A_{TM, c}^+
\end{bmatrix} = \begin{bmatrix}
\frac{2}{\kappa_s} & 0 & -k_s & 0 \\
\frac{2}{\kappa_s} & 0 & -k_s & 0 \\
-k_s & 0 & 2 & \kappa_s + k_s \\
-k_s & 0 & 2 & \kappa_s + k_s
\end{bmatrix} = \tilde{0}. \tag{22}
$$

and

$$\begin{bmatrix}
\hat{B}_2 & A_{TM, s}^+ & \hat{B}_1 & A_{TM, c}^+
\end{bmatrix} = \begin{bmatrix}
\frac{2}{\kappa_s} & 0 & -k_s & 0 \\
\frac{2}{\kappa_s} & 0 & -k_s & 0 \\
-k_s & 0 & 2 & \kappa_s + k_s \\
-k_s & 0 & 2 & \kappa_s + k_s
\end{bmatrix} = \tilde{0}. \tag{23}
$$
In this case the polar orientation of the optical axis can have an arbitrary value, which may break the anisotropy symmetry with respect to the $y-z$ plane [24]. However, importantly, eigenmodes can also be expressed as even and odd modes, and DPs can exist provided the structure is symmetric in refractive index.

[34] A. F. Oskooi et al., Computer Physics Communications 181, 687 (2010).